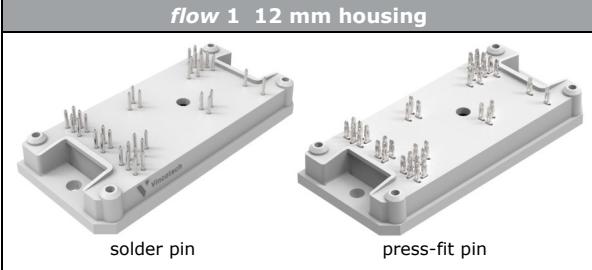
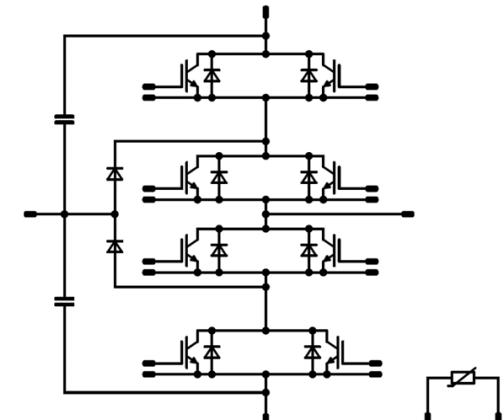




Vincotech

flowNPC 1		1200 V / 150 A
Features		
	<ul style="list-style-type: none">• NPC inverter topology• Optimized for full rated bi-directional usage (4 quadrant)• High-speed IGBT in all switch positions• Integrated NTC• Low inductive design with integrated DC capacitor• <i>flow 1</i> 12mm package	
Target applications		Schematic
	<ul style="list-style-type: none">• Solar inverter• UPS	
Types		
	<ul style="list-style-type: none">• 10-FY07NPA150SM02-L365F08• 10-PY07NPA150SM02-L365F08Y	

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Buck Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	83	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	450	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	128	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Buck Diode				
Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	87	A
Repetitive peak forward current	I_{FRM}		300	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	113	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Out. Boost Switch

Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$	83	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	450	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	128	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Out. Boost Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	87	A
Repetitive peak forward current	I_{FRM}		300	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	113	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Out. Boost Inverse Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	106	A
Repetitive peak forward current	I_{FRM}		300	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	149	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

DC Link Capacitor

Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55...+125	$^\circ\text{C}$



Maximum Ratings

$T_j = 25 \text{ } ^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{\text{jmax}} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance		solder pin \ press-fit pin		8,07 \ 7,86	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Buck Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0015	25	3,3	4	4,7	V
Collector-emitter saturation voltage	V_{CESat}		15		150	25 125 150		1,70 1,88 1,93	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25			80	µA
Gate-emitter leakage current	I_{GES}		20	0		25			240	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25	25		8600		pF
Output capacitance	C_{oes}							150		
Reverse transfer capacitance	C_{res}							32		
Gate charge	Q_g		15	520	150	25		332		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						0,74		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	-5 / 15	700	90	25		48		ns
Rise time	t_r					125		46		
Turn-off delay time	$t_{d(off)}$					150				
Fall time	t_f	$Q_{fFWD} = 3,8 \mu\text{C}$ $Q_{fFWD} = 7,1 \mu\text{C}$ $Q_{fFWD} = 8,1 \mu\text{C}$	-5 / 15	700	90	25		11		mWs
Turn-on energy (per pulse)	E_{on}					125		12		
Turn-off energy (per pulse)	E_{off}					150		13		
						25		133		
						125		152		
						150		156		
						25		7		
						125		7		
						150		8		
						25		0,737		
						125		1,118		
						150		1,210		
						25		0,367		
						125		0,706		
						150		0,798		



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Buck Diode

Static

Forward voltage	V_F				150	25 125 150		1,67 1,67 1,66	1,77	V
Reverse leakage current	I_R			650		25			7,6	μA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,84		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 7000 \text{ A}/\mu\text{s}$ $di/dt = 7124 \text{ A}/\mu\text{s}$ $di/dt = 6971 \text{ A}/\mu\text{s}$	-5 / 15	700	90	25		110		A
Reverse recovery time	t_{rr}					125		143		
						150		151		
Recovered charge	Q_r					25		52		ns
						125		85		
Reverse recovered energy	E_{rec}					150		96		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		3,795		μC
						125		7,081		
						150		8,085		
						25		0,853		
						125		1,613		mWs
						150		1,849		
						25		2642		
						125		2119		
						150		2131		$A/\mu\text{s}$



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit	
		V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_j [°C]	V_{GS} [V]	V_{DS} [V]	I_F [A]	Min	Typ	Max

Out. Boost Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0015	25		3,3	4	4,7	V
Collector-emitter saturation voltage	V_{CESat}		15		150	25 125 150			1,70 1,88 1,93	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25				80	µA
Gate-emitter leakage current	I_{GES}		20	0		25				240	nA
Internal gate resistance	r_g								none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25	25			8600		pF
Output capacitance	C_{oes}								150		
Reverse transfer capacitance	C_{res}								32		
Gate charge	Q_g		15	520	150	25			332		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)							0,74		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	-5 / 15	700	90	25		50			ns
Rise time	t_r					125		51			
						150		50			
Turn-off delay time	$t_{d(off)}$					25		11			
						125		13			
Fall time	t_f					150		14			
Turn-on energy (per pulse)	E_{on}	$Q_{f,FWD} = 3,6 \mu\text{C}$ $Q_{f,FWD} = 6,9 \mu\text{C}$ $Q_{f,FWD} = 7,9 \mu\text{C}$				25		114			mWs
						125		134			
						150		139			
Turn-off energy (per pulse)	E_{off}					25		5			
						125		7			
						150		8			
						25		1,100			
						125		1,773			
						150		1,921			
						25		0,243			
						125		0,621			
						150		0,719			



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Out. Boost Diode

Static

Forward voltage	V_F				150	25 125 150		1,67 1,67 1,66	1,77		V
Reverse leakage current	I_R			650		25			7,6		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,84		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 5600 \text{ A/}\mu\text{s}$ $di/dt = 6000 \text{ A/}\mu\text{s}$ $di/dt = 5796 \text{ A/}\mu\text{s}$	-5 / 15	700	90	25		90			A
Reverse recovery time	t_{rr}					125		117			
						150		121			
Recovered charge	Q_r					25		61			ns
						125		97			
Reverse recovered energy	E_{rec}					150		109			µC
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		3,603			
						125		6,937			
						150		7,941			
						25		0,692			mWs
						125		1,331			
						150		1,529			
						25		1618			A/µs
						125		1020			
						150		864			

Out. Boost Inverse Diode

Static

Forward voltage	V_F				150	25 125 150		1,66 1,61 1,59	2		V
Reverse leakage current	I_R			650		25 150			1,8		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,64		K/W
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DC Link Capacitor

Capacitance	C							300		nF
Tolerance							-10		+10	%
Dissipation factor		$f = 1 \text{ kHz}$				25			2,5	%



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Characteristic Values

Parameter	Symbol	Conditions					Value			Unit		
		V_{GE} [V]	V_{CE} [V]	I_c [A]	V_{GS} [V]	V_{DS} [V]	I_D [A]	T_1 [°C]	I_F [A]	Min	Typ	Max

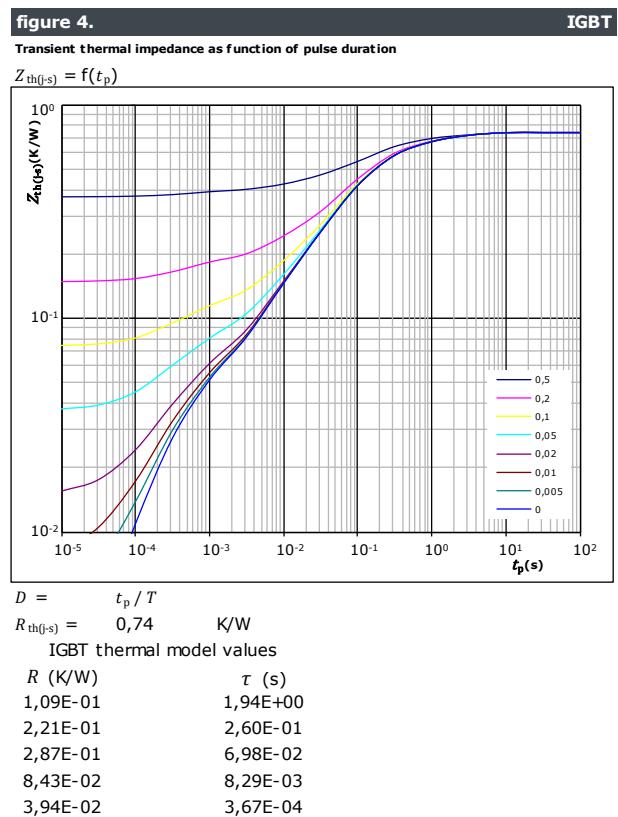
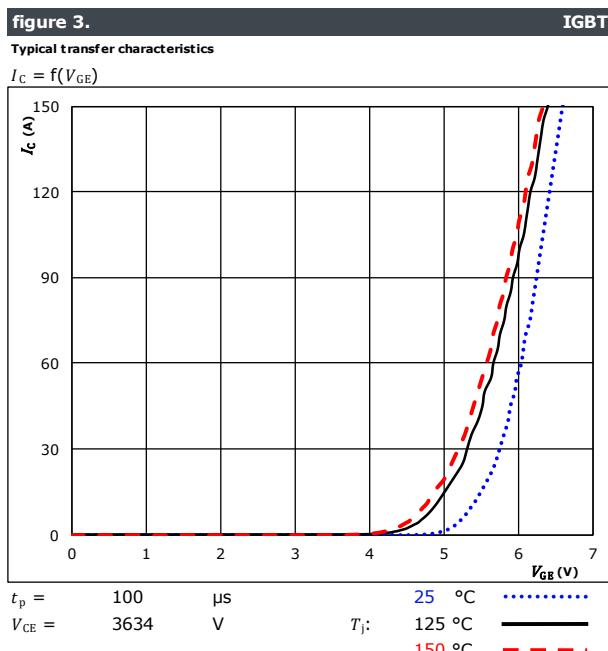
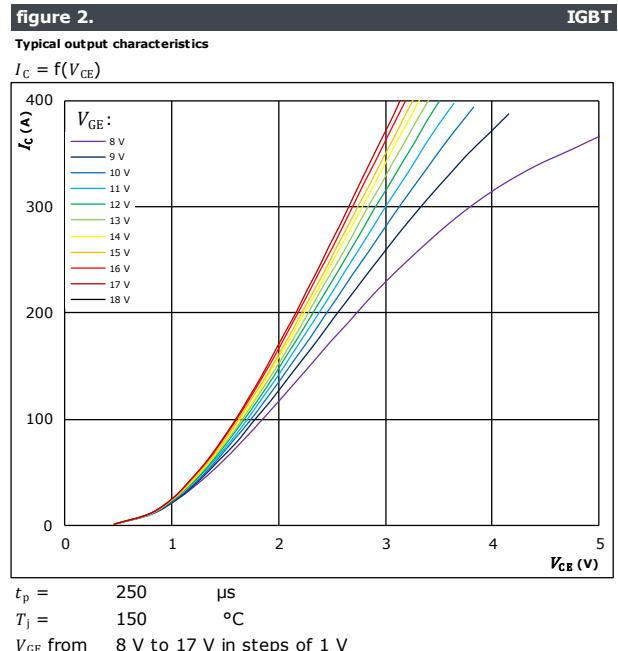
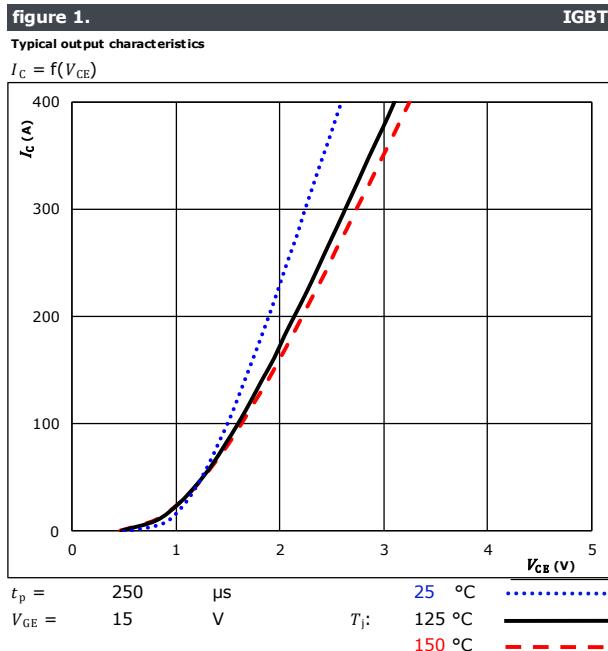
Thermistor

Rated resistance	R					25		22			kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5		%
Power dissipation	P					25		5			mW
Power dissipation constant						25		1,5			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962			K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000			K
Vincotech NTC Reference									I		



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Buck Switch Characteristics





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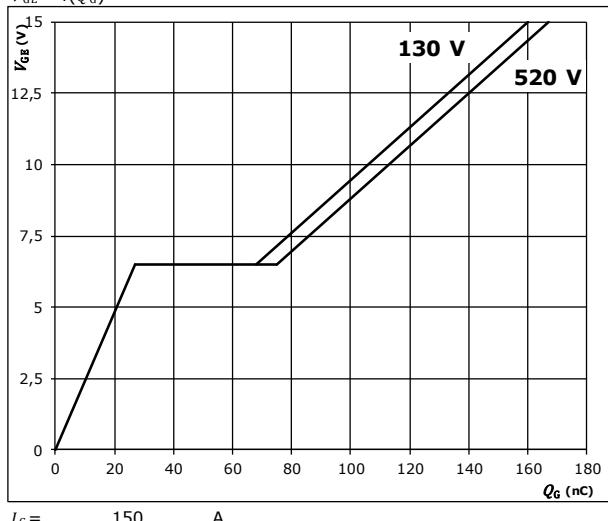
**10-FY07NPA150SM02-L365F08 /
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datasheet

Buck Switch Characteristics

figure 5.

Gate voltage vs gate charge

$$V_{GE} = f(Q_G)$$

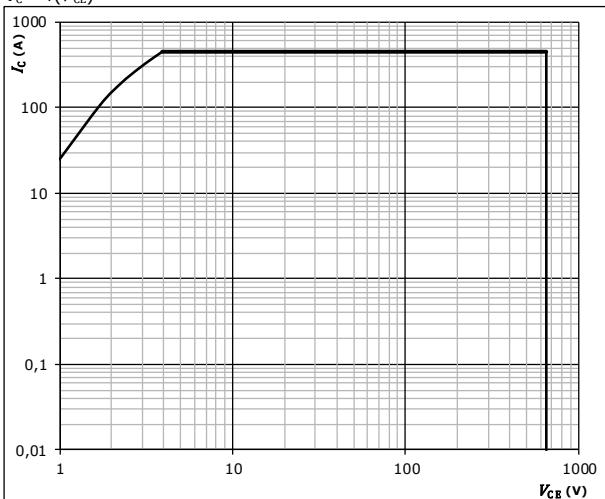


IGBT

figure 6.

Safe operating area

$$I_C = f(V_{CE})$$



$D =$ single pulse

$T_s =$ 80 °C

$V_{GE} =$ ±15 V

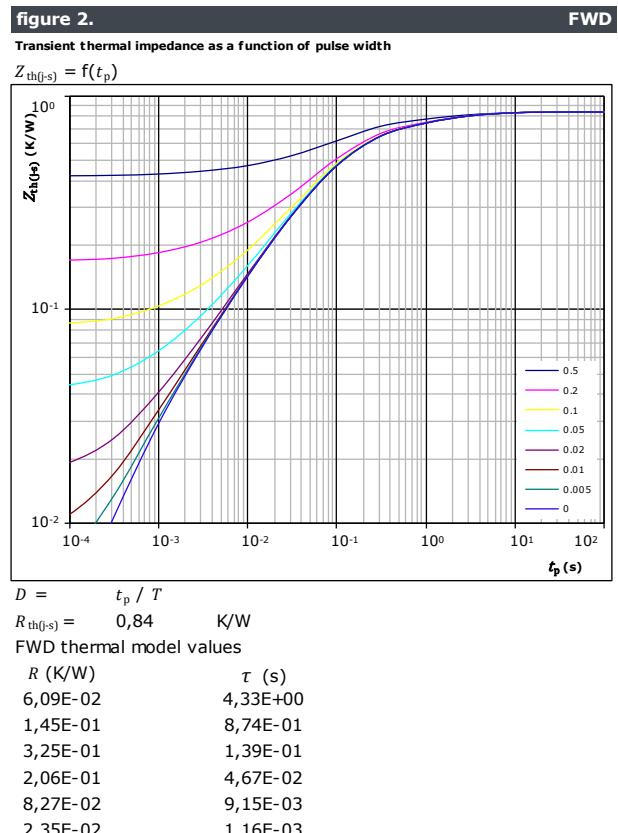
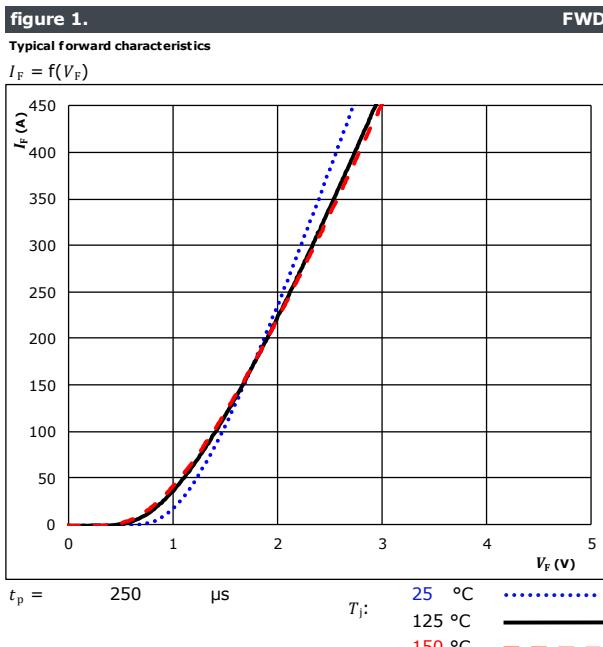
$T_j = T_{jmax}$



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datasheet

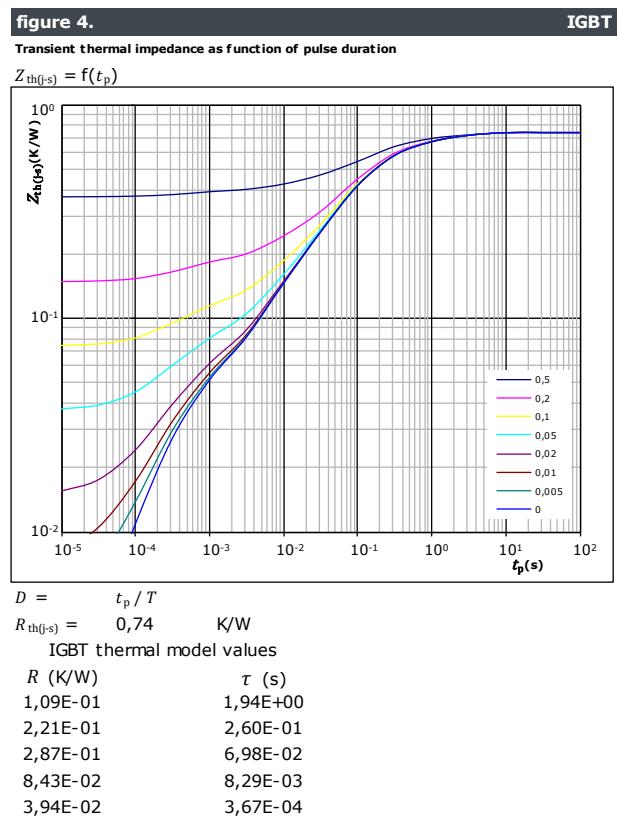
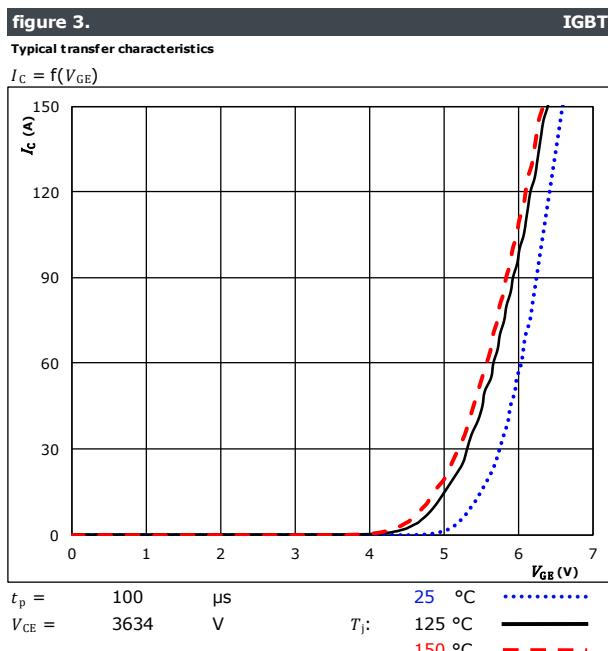
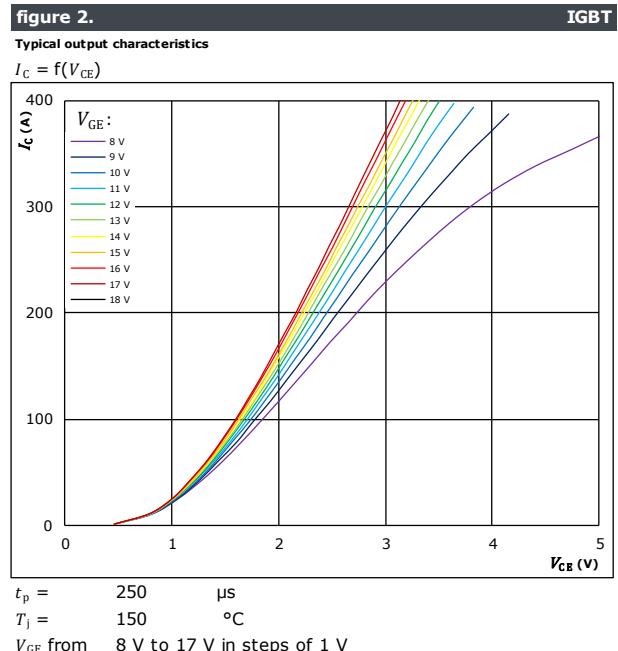
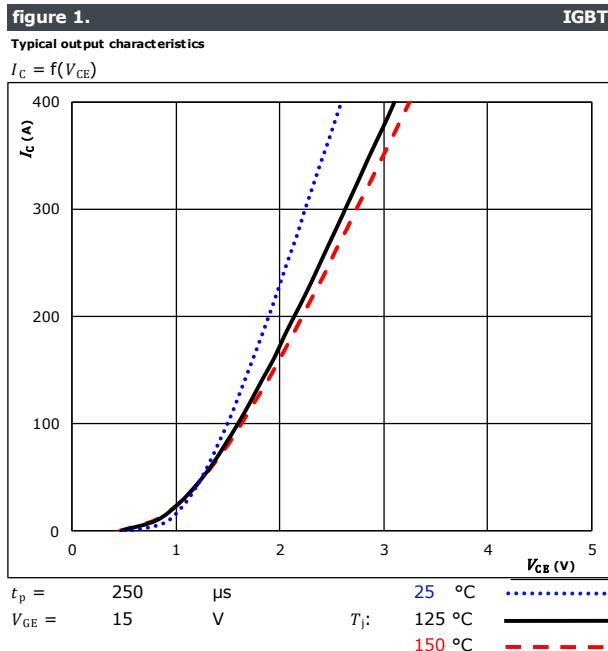
Buck Diode Characteristics





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Out. Boost Switch Characteristics





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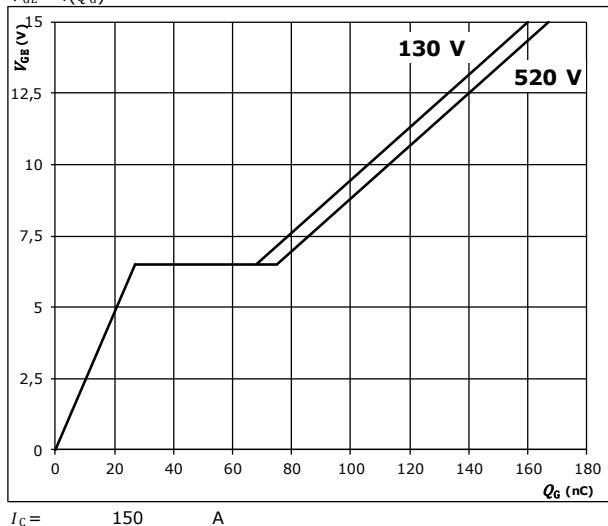
**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

Out. Boost Switch Characteristics

figure 5.

Gate voltage vs gate charge

$$V_{GE} = f(Q_G)$$

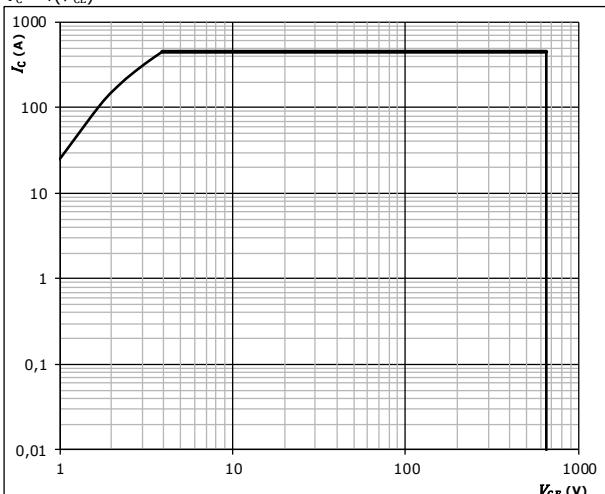


IGBT

figure 6.

Safe operating area

$$I_C = f(V_{CE})$$



$D =$ single pulse

$T_s =$ 80 °C

$V_{GE} =$ ±15 V

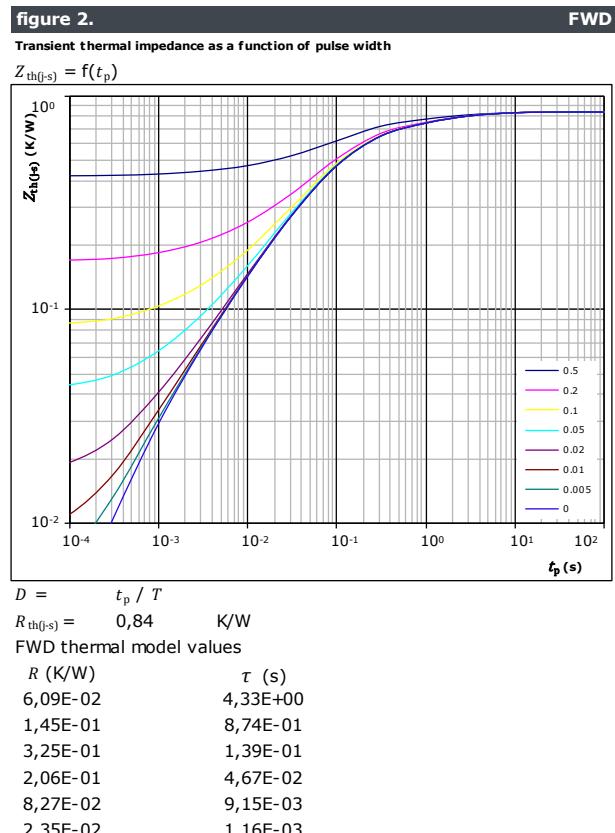
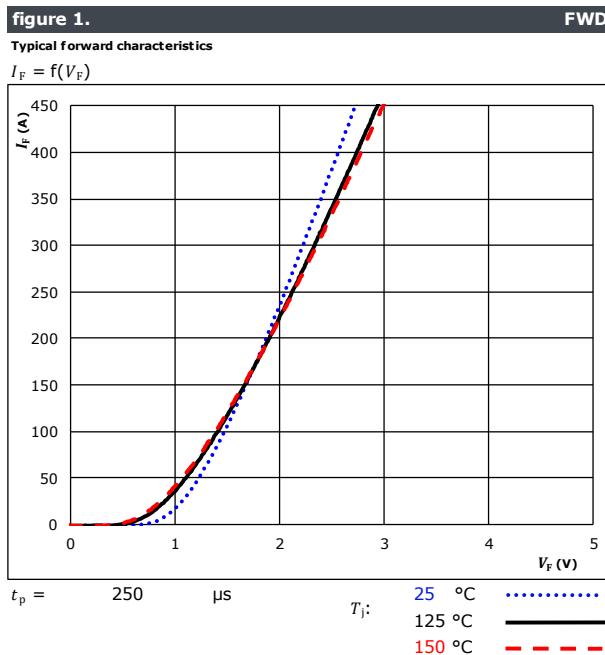
$T_j =$ T_{jmax}



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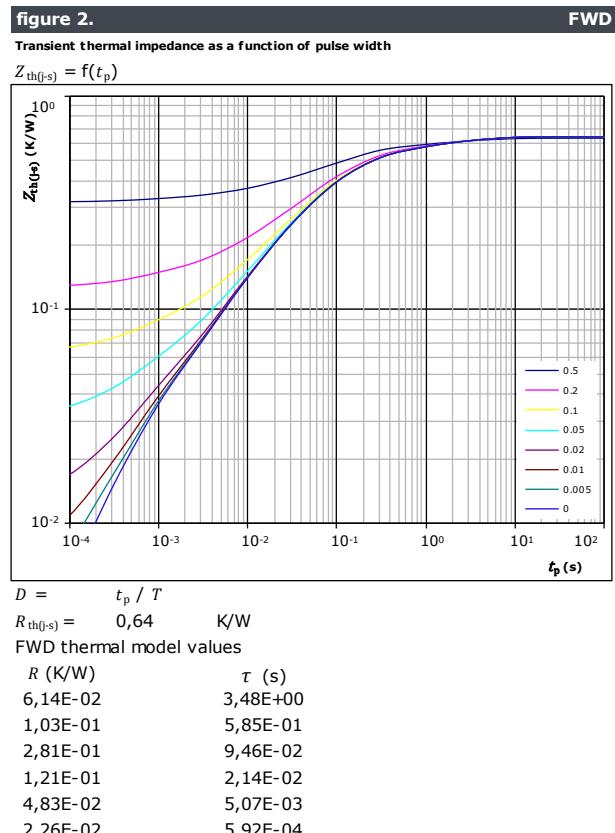
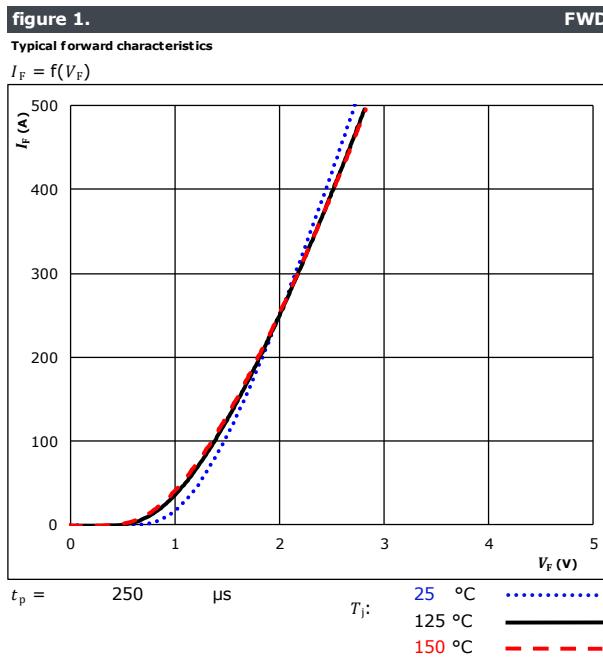
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datasheet

Out. Boost Diode Characteristics

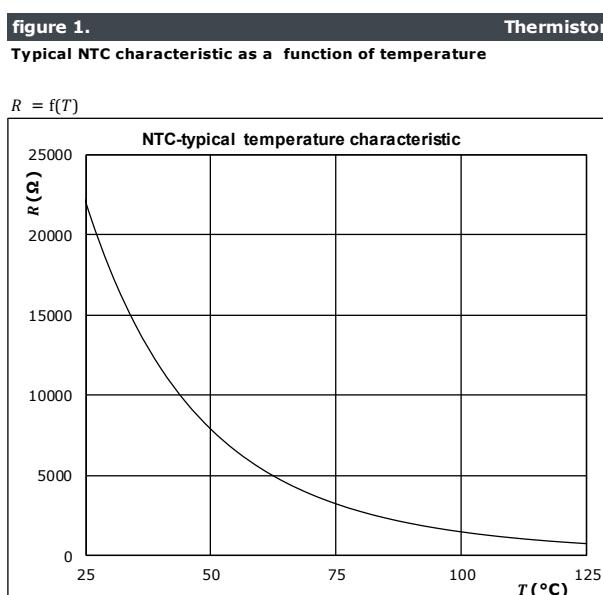




Out. Boost Inverse Diode Characteristics

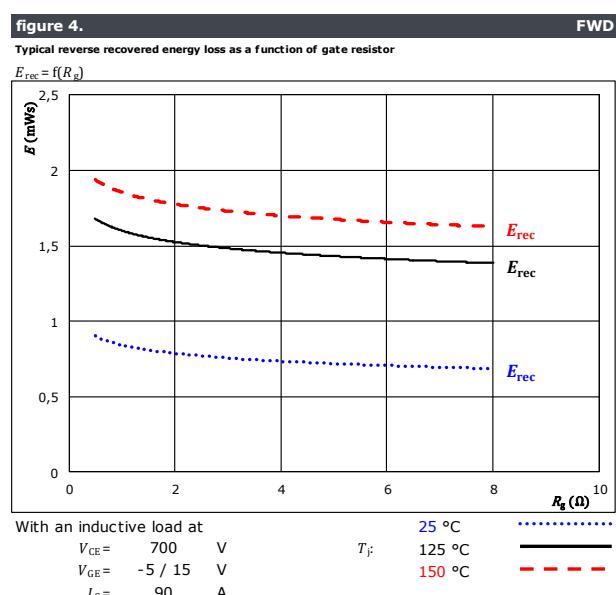
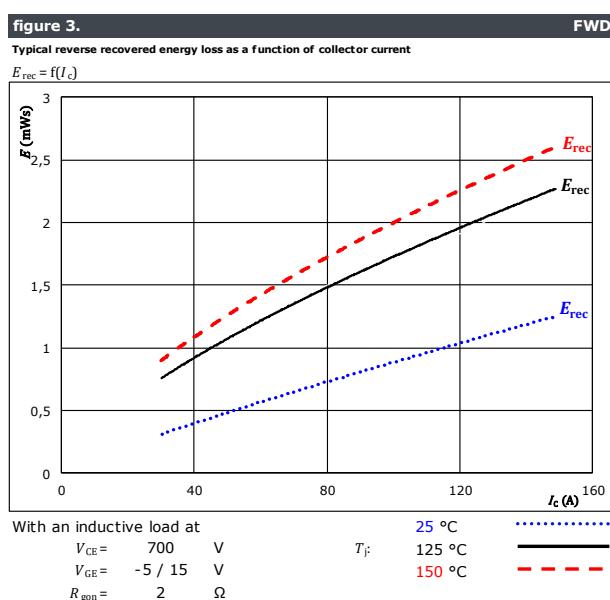
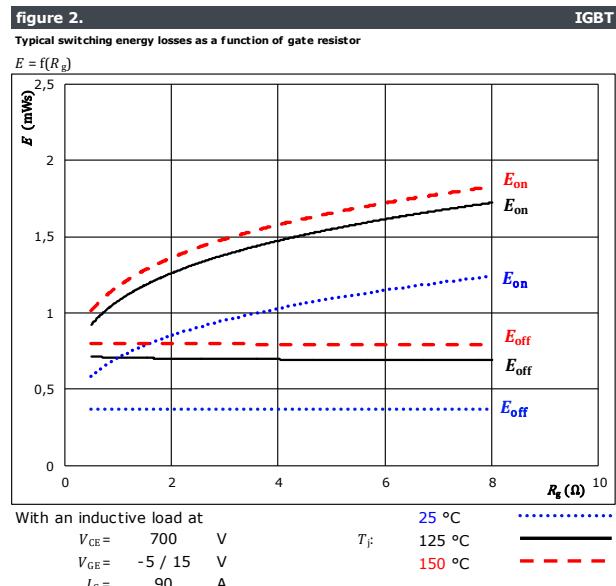
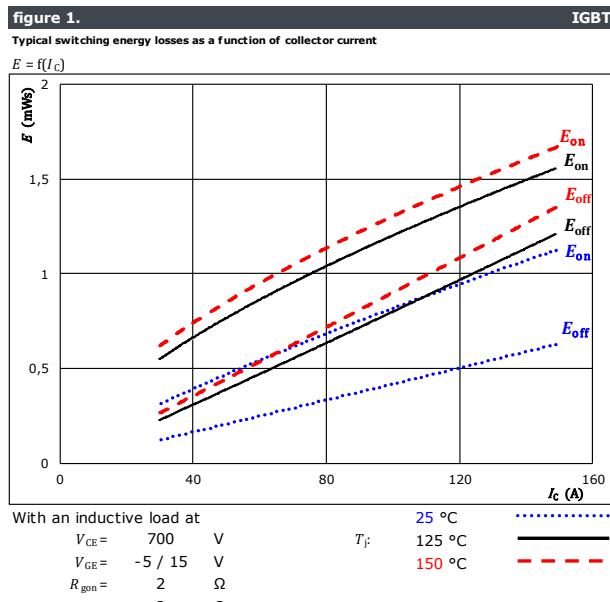


Thermistor Characteristics





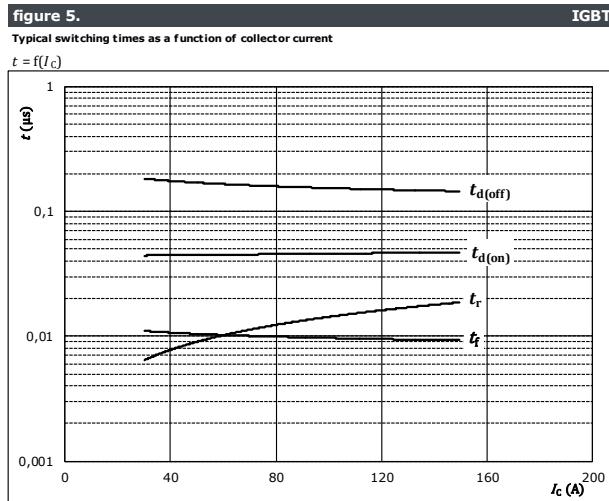
Buck Switching Characteristics





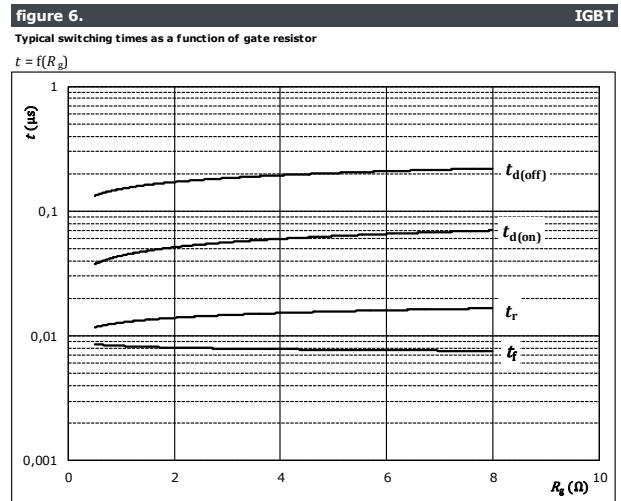
Vincotech

Buck Switching Characteristics



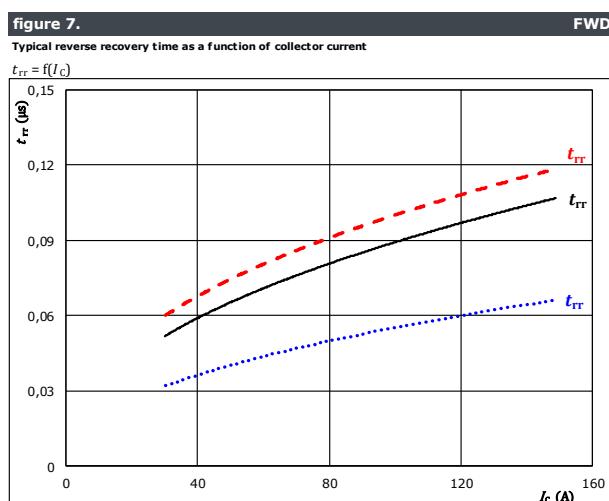
With an inductive load at

$T_J = 150^\circ\text{C}$
 $V_{CE} = 700 \text{ V}$
 $V_{GE} = -5 / 15 \text{ V}$
 $R_{gon} = 2 \Omega$
 $R_{goff} = 2 \Omega$



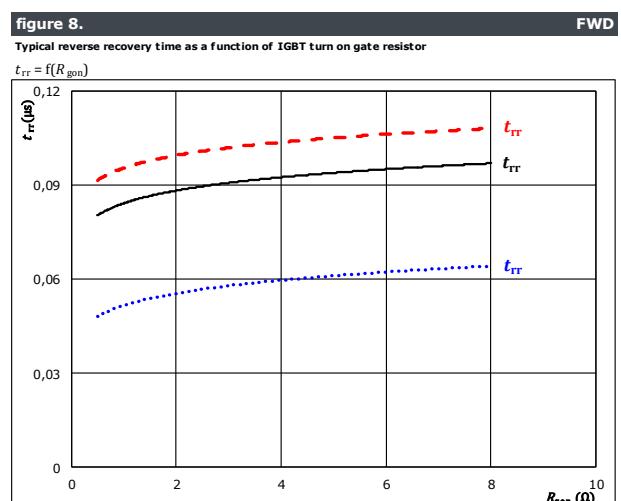
With an inductive load at

$T_J = 150^\circ\text{C}$
 $V_{CE} = 700 \text{ V}$
 $V_{GE} = -5 / 15 \text{ V}$
 $I_C = 90 \text{ A}$



With an inductive load at

$V_{CE} = 700 \text{ V}$
 $V_{GE} = -5 / 15 \text{ V}$
 $R_{gon} = 2 \Omega$



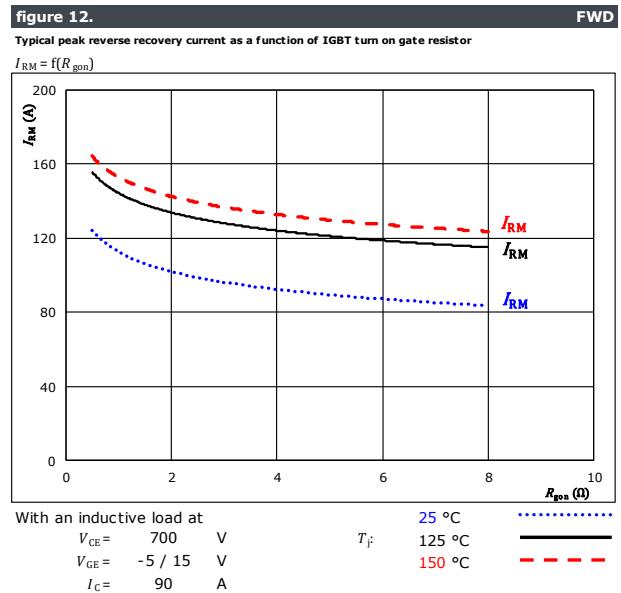
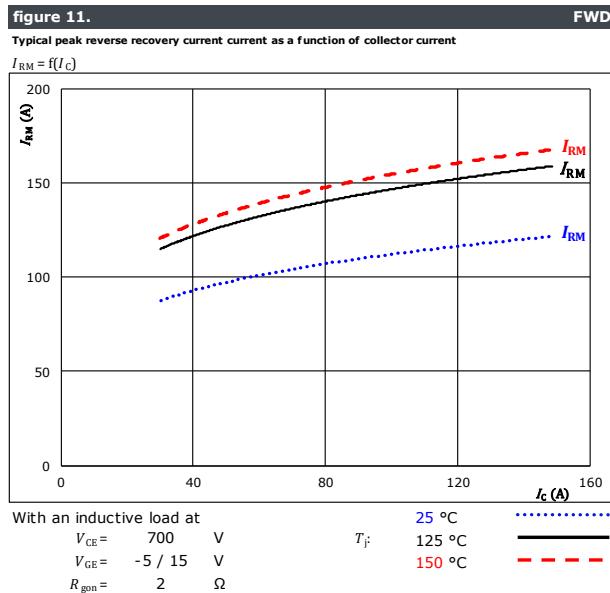
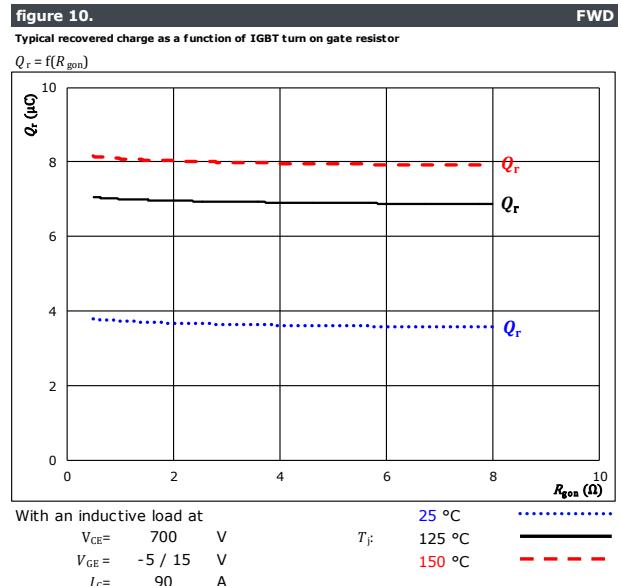
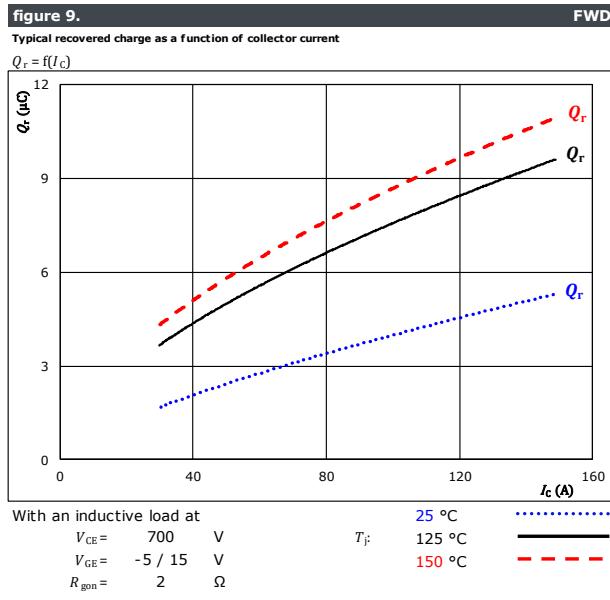
With an inductive load at

$V_{CE} = 700 \text{ V}$
 $V_{GE} = -5 / 15 \text{ V}$
 $I_C = 90 \text{ A}$



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Buck Switching Characteristics





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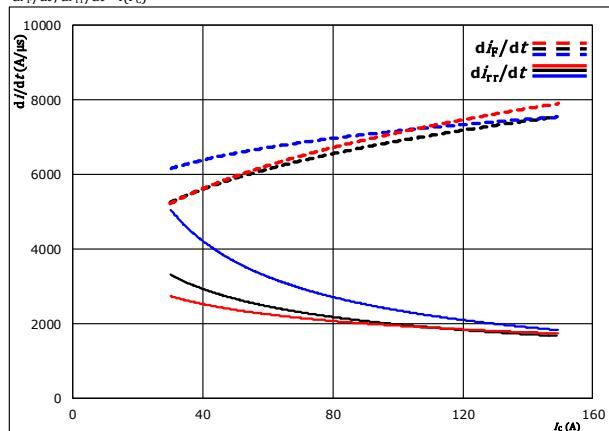
**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

Buck Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_F/dt, di_{rr}/dt = f(I_C)$



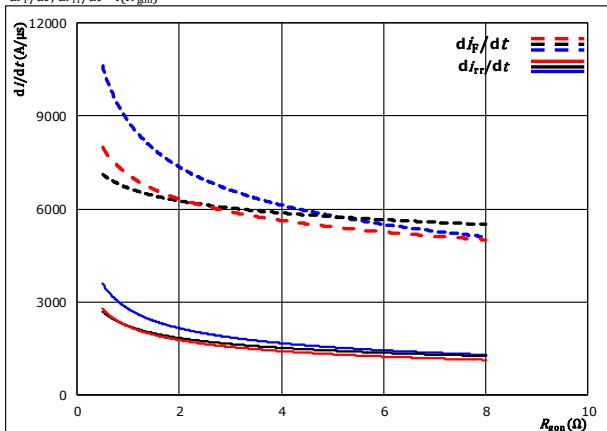
With an inductive load at

$V_{CE} =$	700	V	$T_f =$	25 °C
$V_{GE} =$	-5 / 15	V		125 °C
$R_{gon} =$	2	Ω		150 °C

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$di_F/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

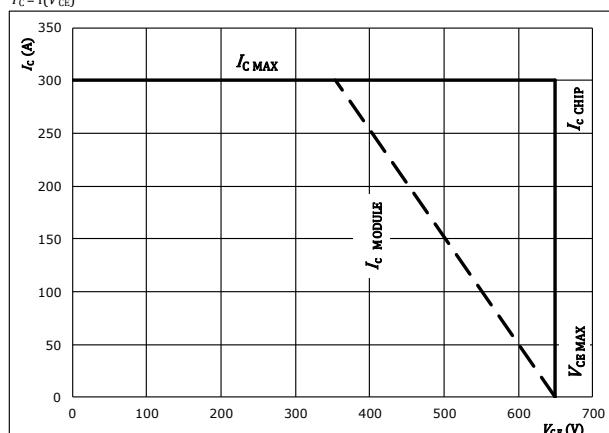
$V_{CE} =$	700	V	$T_f =$	25 °C
$V_{GE} =$	-5 / 15	V		125 °C
$I_C =$	90	A		150 °C

figure 15.

IGBT

Reverse bias safe operating area

$I_C = f(V_{CE})$



At

$T_f =$	125	°C
$R_{gon} =$	2	Ω
$R_{goff} =$	2	Ω



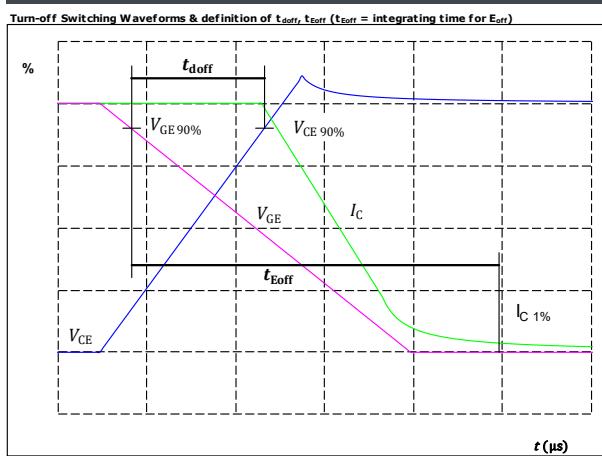
Buck Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	2 Ω
R_{goff}	=	2 Ω

figure 1.

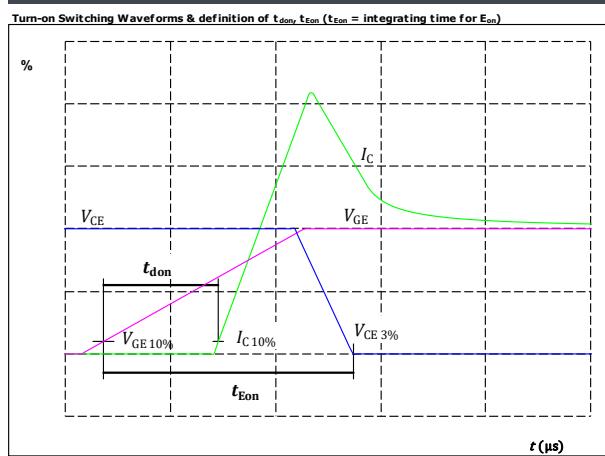
IGBT



$V_{GE}(0\%) = -5 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_{doff} = 152 \text{ ns}$

figure 2.

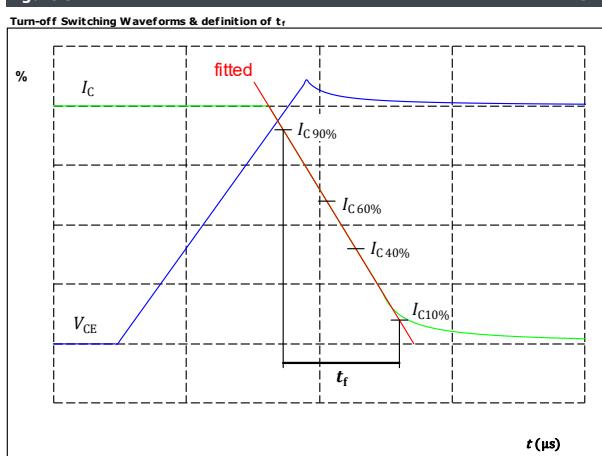
IGBT



$V_{GE}(0\%) = -5 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_{don} = 46 \text{ ns}$

figure 3.

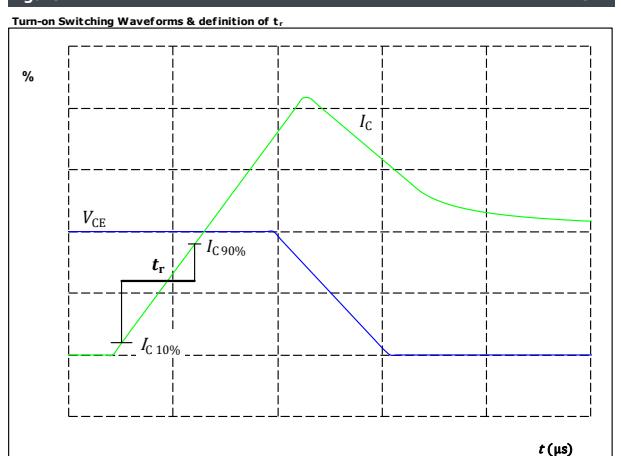
IGBT



$V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_f = 7 \text{ ns}$

figure 4.

IGBT



$V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_r = 12 \text{ ns}$



Vincotech

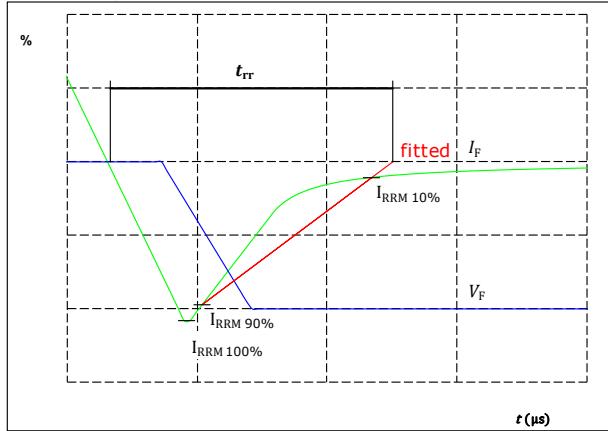
**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

Buck Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

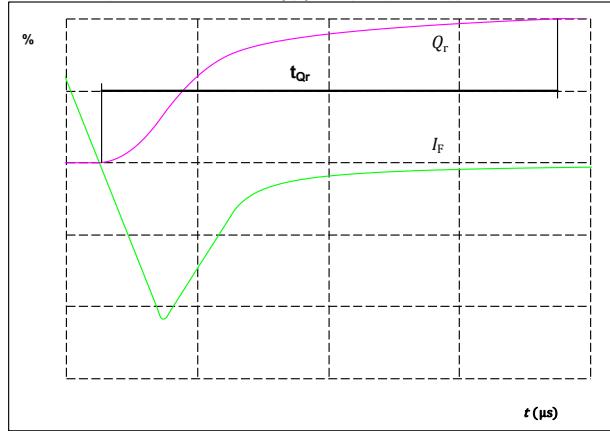


$V_F(100\%) = 700 \text{ V}$
 $I_F(100\%) = 90 \text{ A}$
 $I_{RRM}(100\%) = 143 \text{ A}$
 $t_{rr} = 85 \text{ ns}$

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)



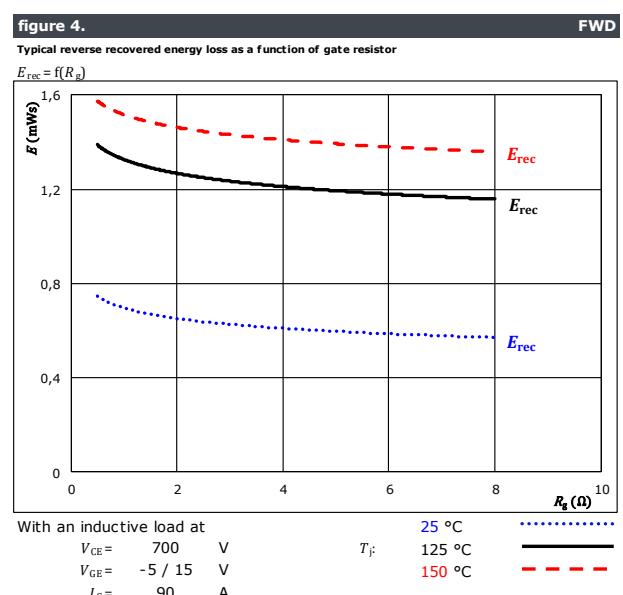
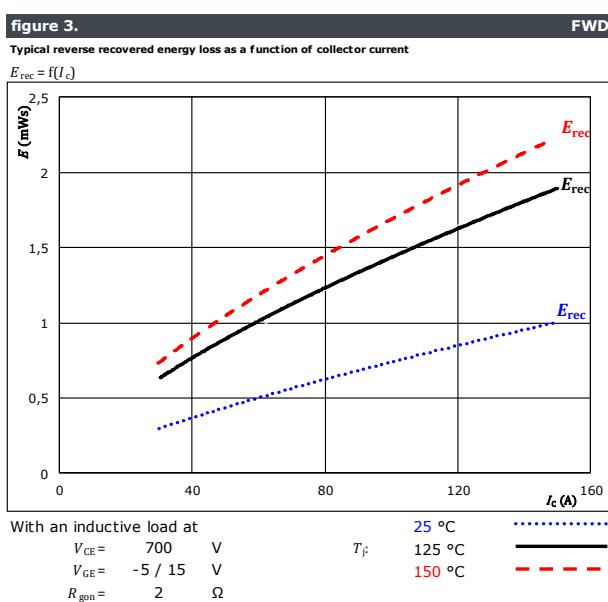
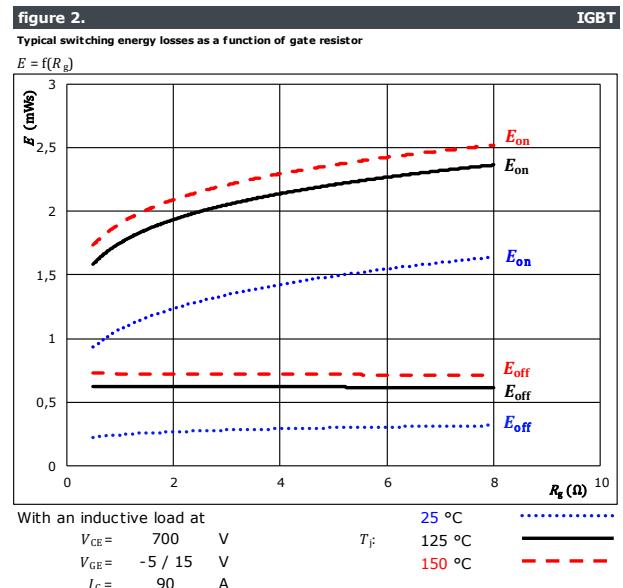
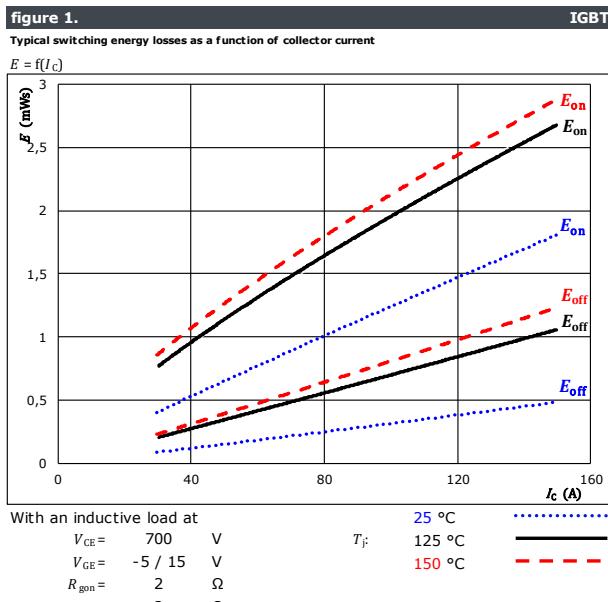
$I_F(100\%) = 90 \text{ A}$
 $Q_r(100\%) = 7,08 \mu\text{C}$



Vincotech

10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y
datasheet

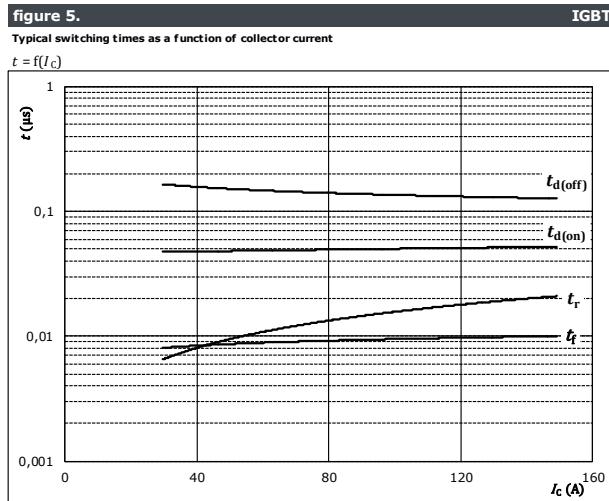
Boost Switching Characteristics





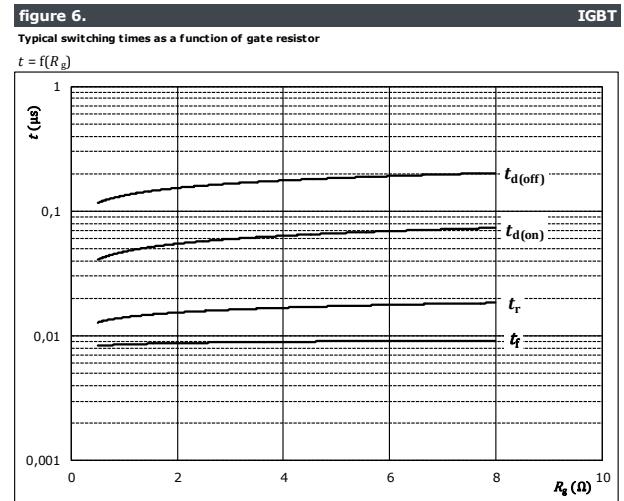
Vincotech

Boost Switching Characteristics



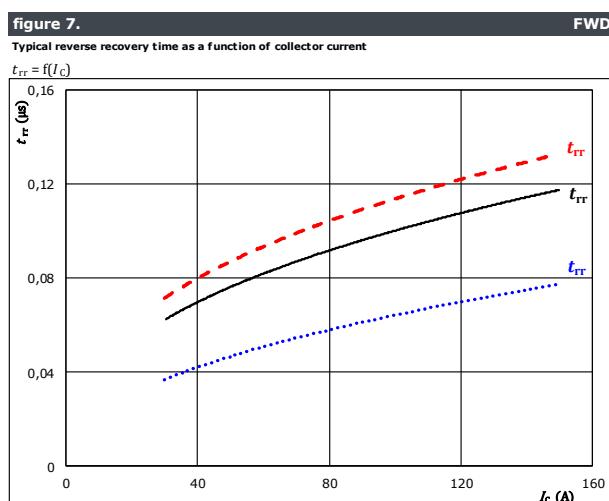
With an inductive load at

$T_j = 150$ °C
 $V_{CE} = 700$ V
 $V_{GE} = -5 / 15$ V
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω



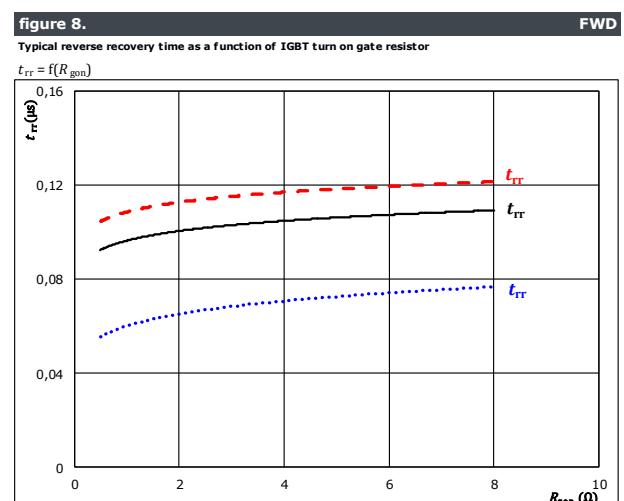
With an inductive load at

$T_j = 150$ °C
 $V_{CE} = 700$ V
 $V_{GE} = -5 / 15$ V
 $I_C = 90$ A



With an inductive load at

$V_{CE} = 700$ V
 $V_{GE} = -5 / 15$ V
 $R_{gon} = 2$ Ω



With an inductive load at

$V_{CE} = 700$ V
 $V_{GE} = -5 / 15$ V
 $I_C = 90$ A

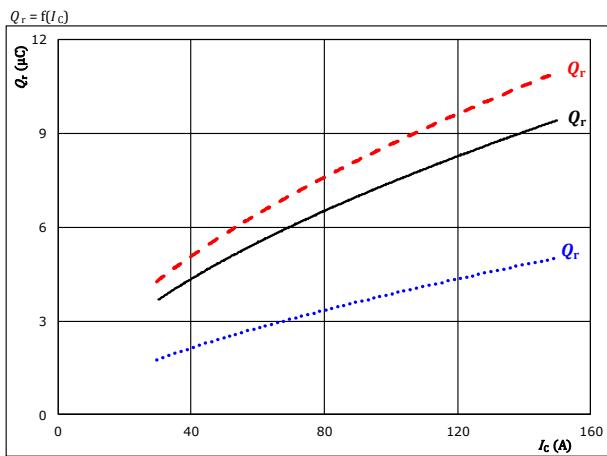


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Boost Switching Characteristics

figure 9.

Typical recovered charge as a function of collector current



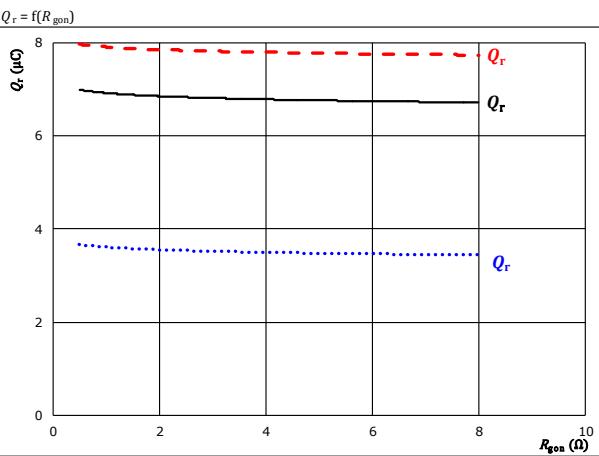
With an inductive load at

$V_{CE} = 700$ V $T_f = 25$ °C $V_{GE} = -5 / 15$ V $T_f = 125$ °C
 $R_{gon} = 2$ Ω $V_{GE} = 150$ °C

FWD

figure 10.

Typical recovered charge as a function of IGBT turn on gate resistor



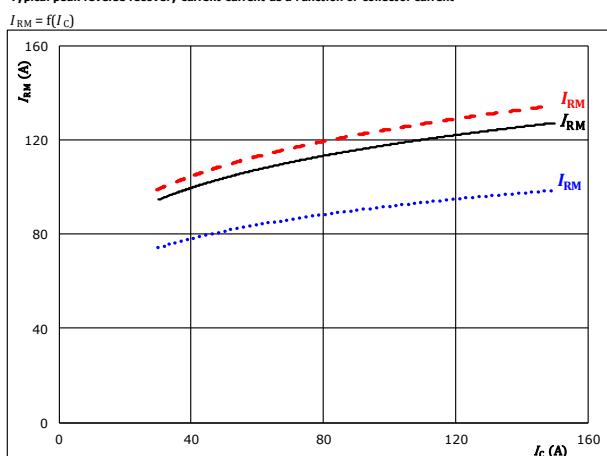
With an inductive load at

$V_{CE} = 700$ V $T_f = 25$ °C $V_{GE} = -5 / 15$ V $T_f = 125$ °C
 $I_C = 90$ A $V_{GE} = 150$ °C

FWD

figure 11.

Typical peak reverse recovery current as a function of collector current



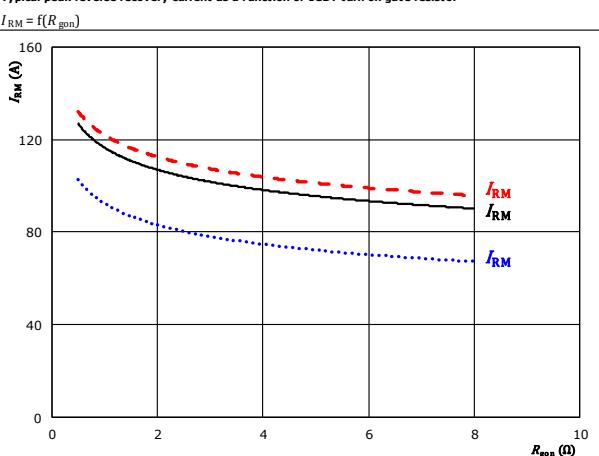
With an inductive load at

$V_{CE} = 700$ V $T_f = 25$ °C $V_{GE} = -5 / 15$ V $T_f = 125$ °C
 $R_{gon} = 2$ Ω $V_{GE} = 150$ °C

FWD

figure 12.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor



With an inductive load at

$V_{CE} = 700$ V $T_f = 25$ °C $V_{GE} = -5 / 15$ V $T_f = 125$ °C
 $I_C = 90$ A $V_{GE} = 150$ °C

FWD



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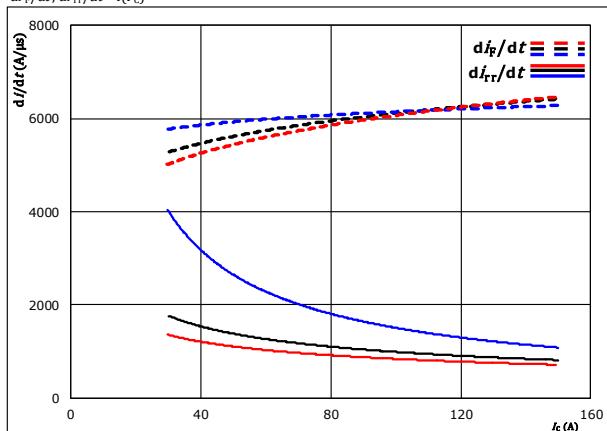
**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

Boost Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_F/dt, di_{rr}/dt = f(I_C)$



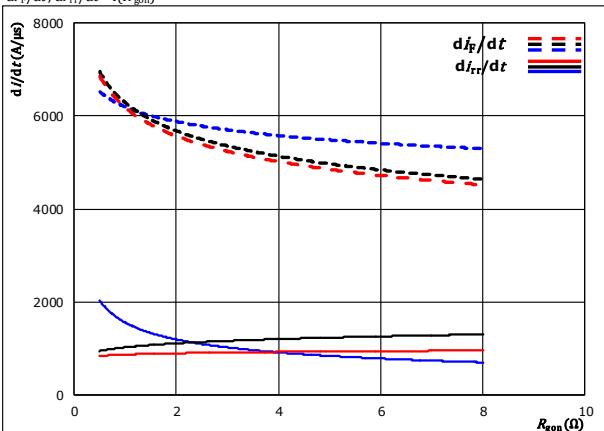
With an inductive load at

$V_{CE} =$	700	V	$T_f =$	25 °C
$V_{GE} =$	-5 / 15	V	$T_f =$	125 °C
$R_{gon} =$	2	Ω	$I_C =$	90 A

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$di_F/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

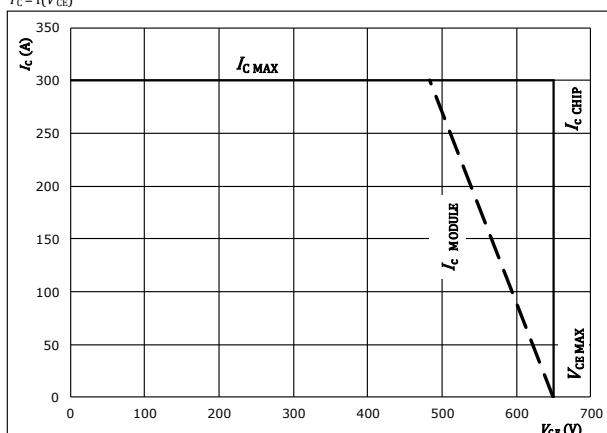
$V_{CE} =$	700	V	$T_f =$	25 °C
$V_{GE} =$	-5 / 15	V	$T_f =$	125 °C
$I_C =$	90	A	$I_C =$	150 °C

figure 15.

IGBT

Reverse bias safe operating area

$I_C = f(V_{CE})$



At

$T_f =$	125	°C
$R_{gon} =$	2	Ω
$R_{goff} =$	2	Ω



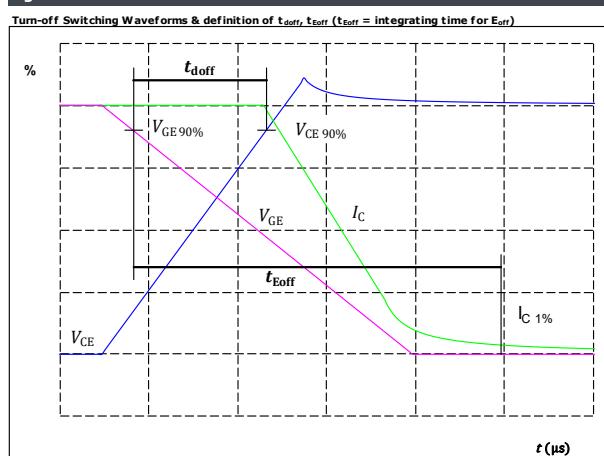
Boost Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	2 Ω
R_{goff}	=	2 Ω

figure 1.

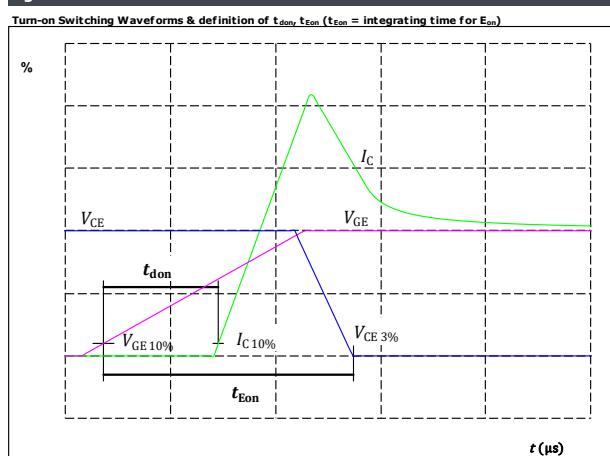
IGBT



$V_{GE\ (0\%)} = -5 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 700 \text{ V}$
 $I_C\ (100\%) = 90 \text{ A}$
 $t_{doff} = 134 \text{ ns}$

figure 2.

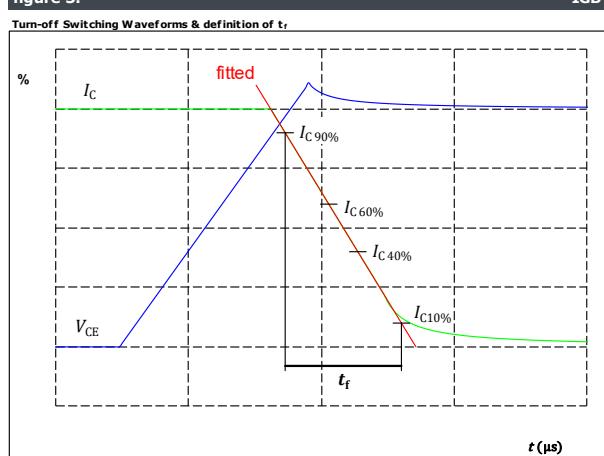
IGBT



$V_{GE\ (0\%)} = -5 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 700 \text{ V}$
 $I_C\ (100\%) = 90 \text{ A}$
 $t_{don} = 51 \text{ ns}$

figure 3.

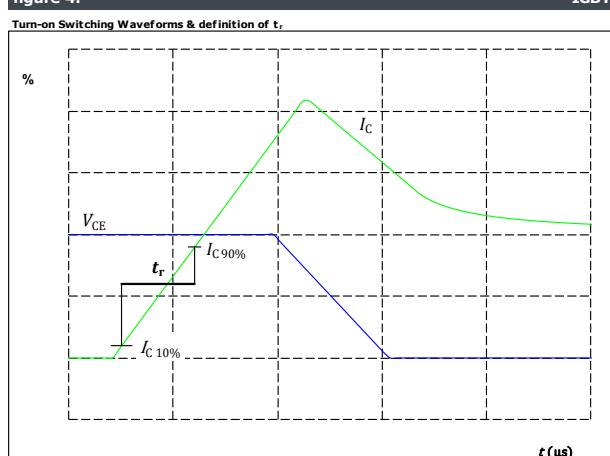
IGBT



$V_C\ (100\%) = 700 \text{ V}$
 $I_C\ (100\%) = 90 \text{ A}$
 $t_f = 7 \text{ ns}$

figure 4.

IGBT



$V_C\ (100\%) = 700 \text{ V}$
 $I_C\ (100\%) = 90 \text{ A}$
 $t_r = 13 \text{ ns}$



Vincotech

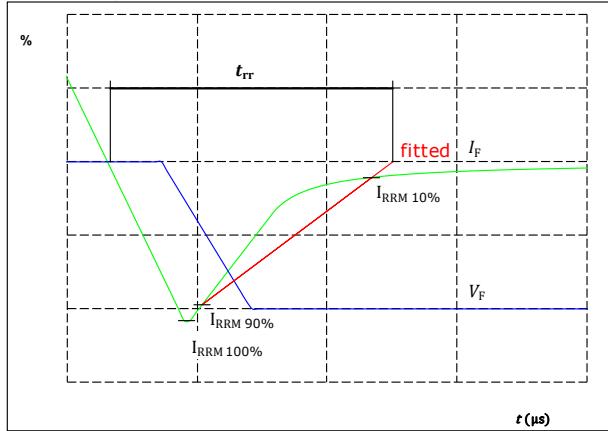
**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

Boost Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

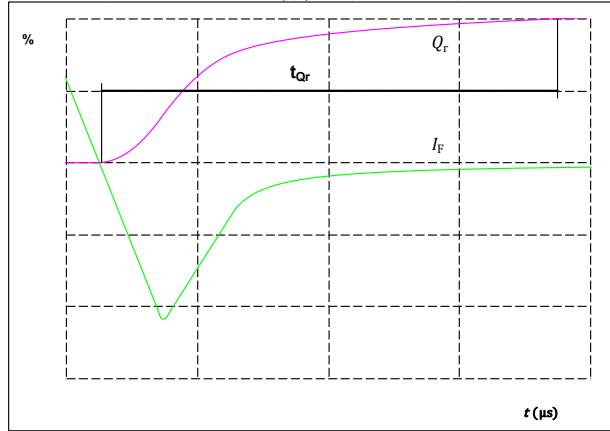


$I_F(100\%) =$	700	V
$I_F(100\%) =$	90	A
$I_{RRM}(100\%) =$	117	A
$t_{rr} =$	97	ns

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)



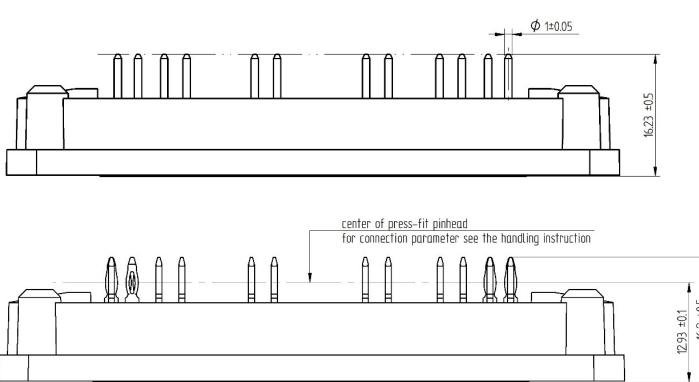
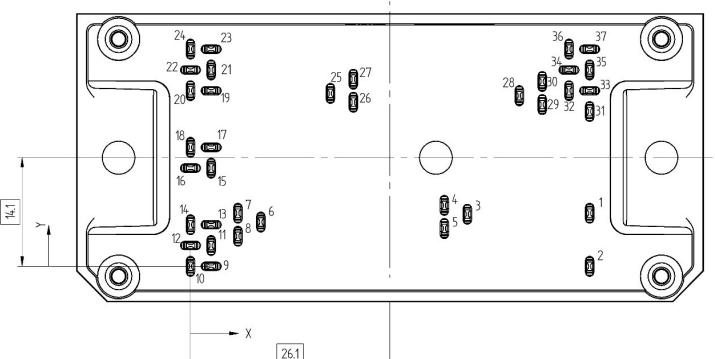
$I_F(100\%) =$	90	A
$Q_r(100\%) =$	6,94	μC



**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

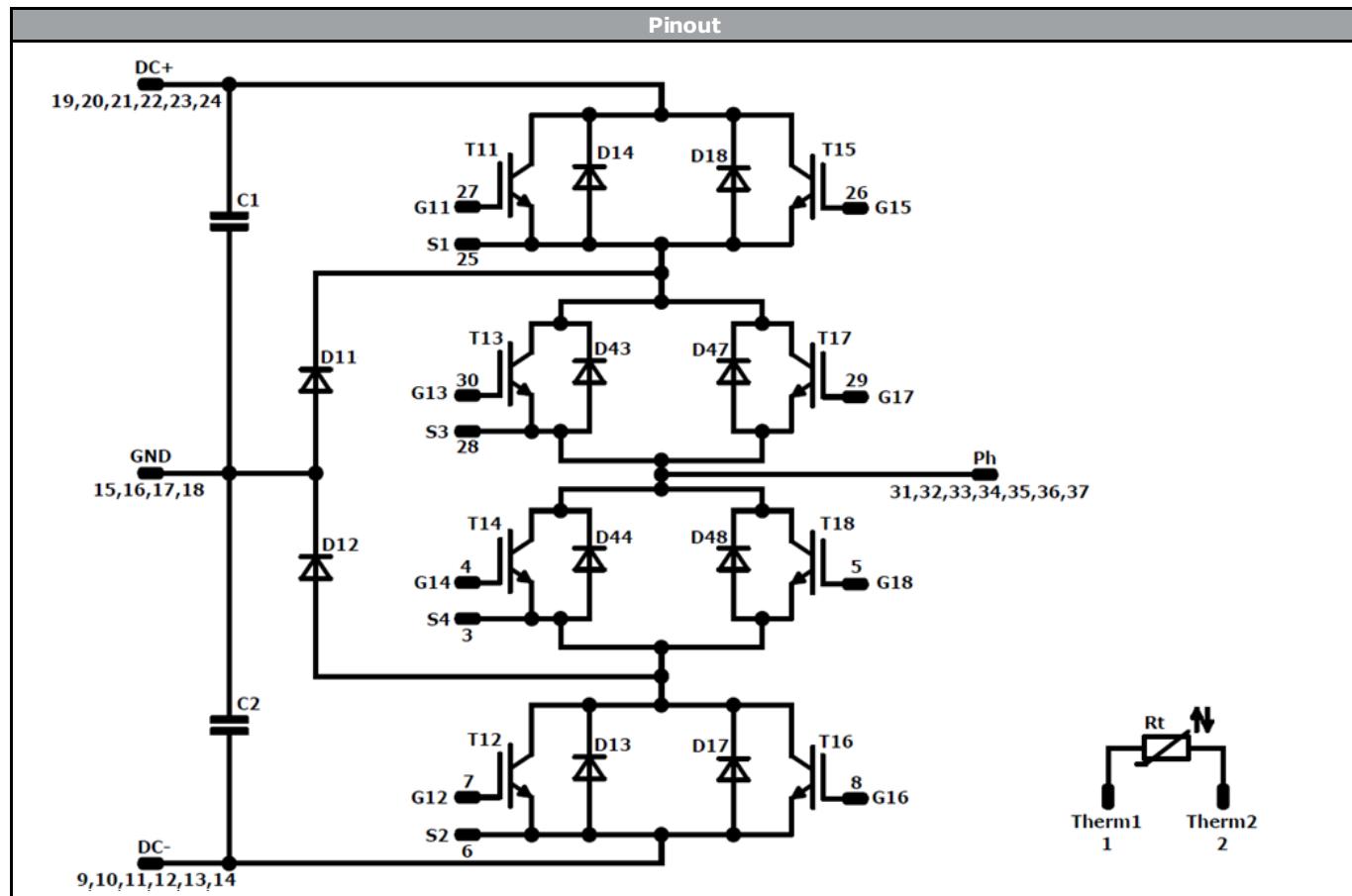
Vincotech

Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 12mm housing with solder pins				10-FY07NPA150SM02-L365F08			
without thermal paste 12mm housing with press-fit pins				10-PY07NPA150SM02-L365F08Y			
with thermal paste 12mm housing with solder pins				10-FY07NPA150SM02-L365F08-/3/			
with thermal paste 12mm housing with press-fit pins				10-PY07NPA150SM02-L365F08Y-/3/			
NN-NNNNNNNNNNNNNN TTTTTWWWWYUL VIN LLLLL SSSS			Text	Name NN-NNNNNNNNNNNNNN-TTTTTW	Date code WWYY	UL & VIN UL VIN	Lot LLLLL
			Datamatrix	Type&Ver TTTTTTWV	Lot number LLLLL	Serial SSSS	Date code WWYY

Outline																																																																																																																																																											
Pin table																																																																																																																																																											
<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>52,2</td><td>6,9</td><td>Therm1</td></tr><tr><td>2</td><td>52,2</td><td>0</td><td>Therm2</td></tr><tr><td>3</td><td>36,2</td><td>6,75</td><td>S4</td></tr><tr><td>4</td><td>33,2</td><td>7,9</td><td>G14</td></tr><tr><td>5</td><td>33,2</td><td>4,9</td><td>G18</td></tr><tr><td>6</td><td>9,2</td><td>5,75</td><td>S2</td></tr><tr><td>7</td><td>6,2</td><td>6,9</td><td>G12</td></tr><tr><td>8</td><td>6,2</td><td>3,9</td><td>G16</td></tr><tr><td>9</td><td>2,7</td><td>0</td><td>DC-</td></tr><tr><td>10</td><td>0</td><td>0</td><td>DC-</td></tr><tr><td>11</td><td>2,7</td><td>2,7</td><td>DC-</td></tr><tr><td>12</td><td>0</td><td>2,7</td><td>DC-</td></tr><tr><td>13</td><td>2,7</td><td>5,4</td><td>DC-</td></tr><tr><td>14</td><td>0</td><td>5,4</td><td>DC-</td></tr><tr><td>15</td><td>2,7</td><td>12,75</td><td>GND</td></tr><tr><td>16</td><td>0</td><td>12,75</td><td>GND</td></tr><tr><td>17</td><td>2,7</td><td>15,45</td><td>GND</td></tr><tr><td>18</td><td>0</td><td>15,45</td><td>GND</td></tr><tr><td>19</td><td>2,7</td><td>22,8</td><td>DC+</td></tr><tr><td>20</td><td>0</td><td>22,8</td><td>DC+</td></tr><tr><td>21</td><td>2,7</td><td>25,5</td><td>DC+</td></tr><tr><td>22</td><td>0</td><td>25,5</td><td>DC+</td></tr><tr><td>23</td><td>2,7</td><td>28,2</td><td>DC+</td></tr><tr><td>24</td><td>0</td><td>28,2</td><td>DC+</td></tr><tr><td>25</td><td>18,3</td><td>22,45</td><td>S1</td></tr><tr><td>26</td><td>21,3</td><td>21,3</td><td>G15</td></tr><tr><td>27</td><td>21,3</td><td>24,3</td><td>G11</td></tr><tr><td>28</td><td>43</td><td>22,15</td><td>S3</td></tr><tr><td>29</td><td>46</td><td>21</td><td>G17</td></tr><tr><td>30</td><td>46</td><td>24</td><td>G13</td></tr><tr><td>31</td><td>52,2</td><td>20,1</td><td>Ph</td></tr><tr><td>32</td><td>49,5</td><td>22,8</td><td>Ph</td></tr><tr><td>33</td><td>52,2</td><td>22,8</td><td>Ph</td></tr><tr><td>34</td><td>49,5</td><td>25,5</td><td>Ph</td></tr><tr><td>35</td><td>52,2</td><td>25,5</td><td>Ph</td></tr><tr><td>36</td><td>49,5</td><td>28,2</td><td>Ph</td></tr><tr><td>37</td><td>52,2</td><td>28,2</td><td>Ph</td></tr></tbody></table>				Pin	X	Y	Function	1	52,2	6,9	Therm1	2	52,2	0	Therm2	3	36,2	6,75	S4	4	33,2	7,9	G14	5	33,2	4,9	G18	6	9,2	5,75	S2	7	6,2	6,9	G12	8	6,2	3,9	G16	9	2,7	0	DC-	10	0	0	DC-	11	2,7	2,7	DC-	12	0	2,7	DC-	13	2,7	5,4	DC-	14	0	5,4	DC-	15	2,7	12,75	GND	16	0	12,75	GND	17	2,7	15,45	GND	18	0	15,45	GND	19	2,7	22,8	DC+	20	0	22,8	DC+	21	2,7	25,5	DC+	22	0	25,5	DC+	23	2,7	28,2	DC+	24	0	28,2	DC+	25	18,3	22,45	S1	26	21,3	21,3	G15	27	21,3	24,3	G11	28	43	22,15	S3	29	46	21	G17	30	46	24	G13	31	52,2	20,1	Ph	32	49,5	22,8	Ph	33	52,2	22,8	Ph	34	49,5	25,5	Ph	35	52,2	25,5	Ph	36	49,5	28,2	Ph	37	52,2	28,2	Ph
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25	18,3	22,45	S1																																																																																																																																																								
26	21,3	21,3	G15																																																																																																																																																								
27	21,3	24,3	G11																																																																																																																																																								
28	43	22,15	S3																																																																																																																																																								
29	46	21	G17																																																																																																																																																								
30	46	24	G13																																																																																																																																																								
31	52,2	20,1	Ph																																																																																																																																																								
32	49,5	22,8	Ph																																																																																																																																																								
33	52,2	22,8	Ph																																																																																																																																																								
34	49,5	25,5	Ph																																																																																																																																																								
35	52,2	25,5	Ph																																																																																																																																																								
36	49,5	28,2	Ph																																																																																																																																																								
37	52,2	28,2	Ph																																																																																																																																																								
				Tolerance of pinpositions ±0,5mm at the end of pins Dimension of coordinate axis is only offset without tolerance																																																																																																																																																							



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T15, T16	IGBT	650V	75A	Buck Switch	Parallel devices with separate control. Values apply to complete device.
D11, D12	FWD	650V	100A	Buck Diode	
T13, T14, T17, T18	IGBT	650V	75A	Out. Boost Switch	Parallel devices with separate control. Values apply to complete device.
D13, D14, D17, D18	FWD	650V	50A	Out. Boost Diode	Parallel devices. Values apply to complete device.
D43, D44, D47, D48	FWD	650V	50A	Out. Boost Inverse Diode	Parallel devices. Values apply to complete device.
C1, C2	Capacitor	630V	-	DC Link Capacitor	
Rt	NTC	-	-	Thermistor	



**10-FY07NPA150SM02-L365F08 /
10-PY07NPA150SM02-L365F08Y**
datasheet

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Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for if no series packaging available packages see vincotech.com website.			

Package data			
Package data for if no series packaging available packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-xY07NPA150SM02-L365F08x-D7-14	22 Jul. 2020	Correct Parallel devices in Identification table	29

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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.